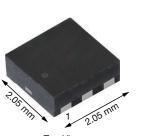
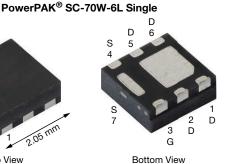
## SQA407CEJW

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**Vishay Siliconix** 

# Automotive P-Channel 20 V (D-S) 175 °C MOSFET





Top View Marking Code: QYXXXX

#### **PRODUCT SUMMARY** V<sub>DS</sub> (V) -20 0.0250 $R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 V$ $R_{DS(on)}(\Omega)$ at $V_{GS}$ = -2.5 V 0.0420 -9 I<sub>D</sub> (A) Configuration Single

### **FEATURES**

- TrenchFET<sup>®</sup> power MOSFET
- AEC-Q101 gualified
- Wettable flank terminals
- 100 % R<sub>q</sub> and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



GC P-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK SC-70W-6L
Lead (Pb)-free and halogen-free	SQA407CEJW (for detailed order number please see <u>www.vishay.com/doc?79776</u> )

ABSOLUTE MAXIMUM RATIN	<b>GS</b> (T <sub>C</sub> = 25 °C, unless	s otherwise notec	ł)	
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V <sub>DS</sub>	-20	V
Gate-source voltage		V <sub>GS</sub>	± 12	v
Continuous drain current <sup>a</sup>	T <sub>C</sub> = 25 °C	I	-9	
	T <sub>C</sub> = 125 °C	- I <sub>D</sub>	-9	
Continuous source current (diode conduction) a		I <sub>S</sub>	-9	А
Pulsed drain current <sup>b</sup>		I <sub>DM</sub>	-36	
Single pulse avalanche current	L = 0.1 mH	I <sub>AS</sub>	-15	
Single pulse avalanche energy	L = 0.1 MH	E <sub>AS</sub>	11.25	mJ
Maximum power dissipation	T <sub>C</sub> = 25 °C	D	13.6	W
	T <sub>C</sub> = 125 °C	P <sub>D</sub>	4.5	vv
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C
Soldering recommendations (peak temperature) <sup>d, e</sup>		-	260	C

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient P	PCB mount <sup>c</sup>	R <sub>thJA</sub>	90	°C/W
Junction-to-case (drain)		R <sub>thJF</sub>	11	0/10

### Notes

a. Package limited

b. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %

c. When mounted on 1" square PCB (FR4 material)

Rework conditions: manual soldering with a soldering iron is not recommended for leadless components Not intended for continuous use with positive gate voltage > 3.0 V e.

f.

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See solder profile (www.vishay.com/doc?73257). The PowerPAK SC-70W-6L is a leadless package and features wettable flank terminals. d. The end of the lead terminal is plated with tin

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static						I	
Drain-source breakdown voltage	V <sub>DS</sub>	V <sub>GS</sub> = 0, I <sub>D</sub> = -250 μA		-20	-	-	V
Gate-source threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	-0.6	-1.0	-1.3		
Gate-source leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 12 V$		-	-	± 100	nA
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>GS</sub> = 0 V V <sub>DS</sub> = -20 V		-	-	-1	
		$V_{GS} = 0 V$	V <sub>DS</sub> = -20 V, T <sub>J</sub> = 125 °C	-	-	-50	μA
		$V_{GS} = 0 V$	V <sub>DS</sub> = -20 V, T <sub>J</sub> = 175 °C	-	-	-150	
On-state drain current <sup>a</sup>	I <sub>D(on)</sub>	$V_{GS} = -4.5 V$	$V_{DS} \ge 5 V$	-8	-	-	А
Drain-source on-state resistance <sup>a</sup>		$V_{GS} = -4.5 V$	I <sub>D</sub> = -4.5 A	-	0.0202	0.0250	Ω
		$V_{GS} = -4.5 V$	$I_D = -4.5 \text{ A}, T_J = 125 \text{ °C}$	-	-	0.0337	
	R <sub>DS(on)</sub>	$V_{GS} = -4.5 V$	$I_D = -4.5 \text{ A}, \text{ T}_J = 175 \ ^\circ\text{C}$	-	-	0.0381	
		$V_{GS} = -2.5 V$	I <sub>D</sub> = -3 A	-	0.0338	0.0420	
Forward transconductance b	9 <sub>fs</sub>	V <sub>DS</sub> :	= -10 V, I <sub>D</sub> = -4 A	I	20	-	S
Dynamic <sup>b</sup>							
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0 V	V <sub>DS</sub> = -10 V, f = 1 MHz	-	1500	2100	pF
Output capacitance	C <sub>oss</sub>			-	219	310	
Reverse transfer capacitance	C <sub>rss</sub>			-	195	275	
Total gate charge <sup>c</sup>	Qg		V <sub>DS</sub> = -10 V, I <sub>D</sub> = -8 A	-	15.7	24	nC
Gate-source charge <sup>c</sup>	Q <sub>gs</sub>	V <sub>GS</sub> = -4.5 V		-	3.6	-	
Gate-drain charge <sup>c</sup>	Q <sub>gd</sub>			-	4.6	-	
Gate resistance	R <sub>g</sub>	f = 1 MHz		1.2	2.45	3.7	Ω
Turn-on delay time <sup>c</sup>	t <sub>d(on)</sub>				16	24	
Rise time <sup>c</sup>	t <sub>r</sub>	$V_{DD}$ = -10 V, R <sub>L</sub> = 4 $\Omega$ I <sub>D</sub> $\cong$ -2.5 A, V <sub>GEN</sub> = -4.5 V, R <sub>g</sub> = 1 $\Omega$		-	22	33	ns
Turn-off delay time <sup>c</sup>	t <sub>d(off)</sub>			-	29	44	
Fall time <sup>c</sup>	t <sub>f</sub>			-	10	15	
Source-Drain Diode Ratings and Charact	eristics						
Pulsed current <sup>a</sup>	I <sub>SM</sub>			I	-	-36	А
Forward voltage	$V_{SD}$	$I_F = -4.5 \text{ A}, V_{GS} = 0$		-	-0.81	-1.2	V
Body diode reverse recovery time	t <sub>rr</sub>			-	13	26	ns
Body diode reverse recovery charge	Q <sub>rr</sub>	I <sub>F</sub> = -2 A, di/dt = 100 A/μs		-	6	12	nC
Reverse recovery fall time	t <sub>a</sub>			-	7	-	ns
Reverse recovery rise time	t <sub>b</sub>			-	6	-	
Body diode peak reverse recovery current	I <sub>RM(REC)</sub>			I	-0.8	-	А

Notes

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %

b. Guaranteed by design, not subject to production testing

c. Independent of operating temperature

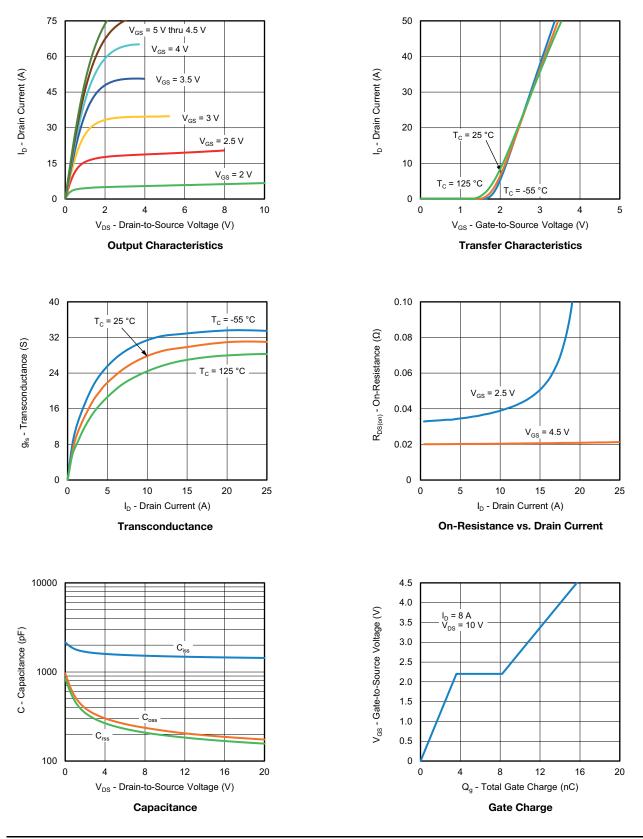
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



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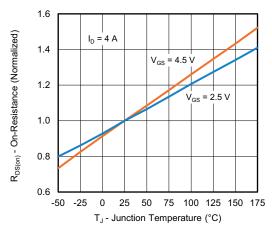
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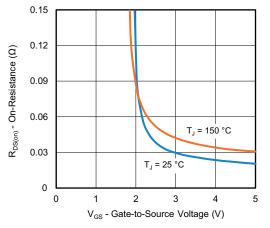


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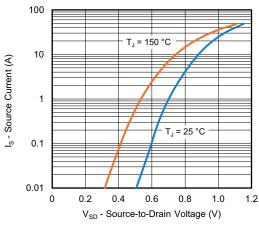
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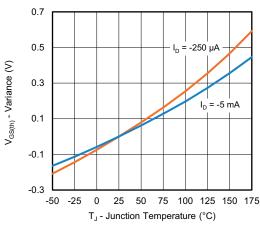
**On-Resistance vs. Junction Temperature** 



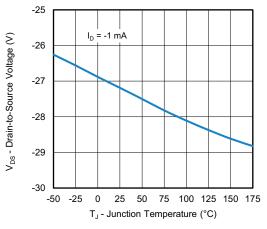
**On-Resistance vs. Gate-to-Source Voltage** 



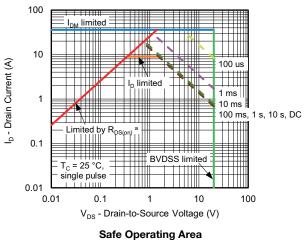
Source-Drain Diode Forward Voltage

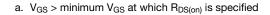


**Threshold Voltage** 



Drain Source Breakdown vs. Junction Temperature





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Note

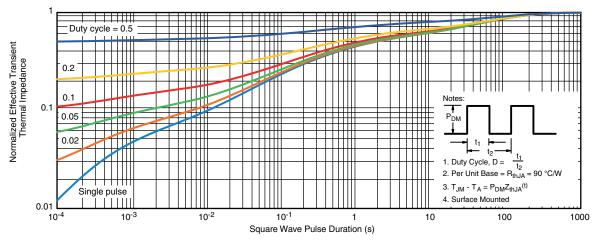
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### THERMAL RATINGS (T<sub>A</sub> = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

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